

Michał Leszczyński

“New trends and challenges in crystal growth in scientific and commercial aspects”



Professor at the Institute of High Pressure Physics UNIPRESS and Vice-president at TopGaN, spin-off from UNIPRESS. Research area: Epitaxial growth, nitride semiconductors, defects in crystals, electronic devices. Author of about 250 papers, cited about 2500 times, Hirsch factor 28. At present, coordinator of workpackages in 10 EU projects on GaN-based devices.